NSN 5962-01-359-5490

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Body Length:
Between 0.540 inches and 0.560 inches
Body Width:
Between 0.442 inches and 0.458 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
W/enable and w/disable and w/clear and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
26 input
Case Outline Source And Designator:
C-12 mil-m-38510
Current Rating Per Characteristic:
80.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 6.25 volts power source
Capitance Rating Per Characteristic:
10.00 input picofarads and 10.00 output picofarads
Time Rating Per Chacteristic:
250.00 nanoseconds access
Memory Device Type:
Eeprom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
32 leadless
Shelf Life:
N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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